Hartmut G Roskos

List of Publications by Year in Descending Order

277 papers	7,680 citations	42 h-index	80 g-index
370 ext. papers	9,391 ext. citations	3 avg, IF	5.6 L-index

#	Paper	IF	Citations
277	Can a terahertz metamaterial sensor be improved by ultra-strong coupling with a high-Q photonic resonator?. *Optics Express*, **2022**, 30, 13659-13672	3.3	0
276	Roadmap of Terahertz Imaging 2021. *Sensors*, **2021**, 21,	3.8	26
275	Antenna-coupled field-effect transistors as detectors for terahertz near-field microscopy. *Nanoscale Advances*, **2021**, 3, 1717-1724	5.1	4
274	Terahertz scattering-type near-field microscopy quantitatively determines the conductivity and charge carrier density of optically doped and impurity-doped silicon. *APL Photonics*, **2021**, 6, 126108	5.2	1
273	Direct nanoscopic observation of plasma waves in the channel of a graphene field-effect transistor. *Light: Science and Applications*, **2020**, 9, 97	16.7	15
272	Terahertz photoconductive waveguide emitter with excitation by a tilted optical pulse front. *Optics Express*, **2020**, 28, 33673-33681	3.3	1
271	Passive Detection and Imaging of Human Body Radiation Using an Uncooled Field-Effect Transistor-Based THz Detector. *Sensors*, **2020**, 20,	3.8	12
270	Intracavity third-harmonic generation in Si:B pumped by intense terahertz pulses. *Physical Review B*, **2020**, 102,	3.3	5
269	A High-Sensitivity AlGaN/GaN HEMT Terahertz Detector With Integrated Broadband Bow-Tie Antenna. *IEEE Transactions on Terahertz Science and Technology*, **2019**, 9, 430-444	3.4	46
268	Design and demonstration of antenna-coupled Schottky diodes in a foundry complementary metal-oxide semiconductor technology for electronic detection of far-infrared radiation. *Journal of Applied Physics*, **2019**, 125, 194501	2.5	4
267	Enhancement of the Monolayer Tungsten Disulfide Exciton Photoluminescence with a Two-Dimensional Material/Air/Gallium Phosphide In-Plane Microcavity. *ACS Nano*, **2019**, 13, 5259-5267	16.7	13
266	Terahertz emission from biased AlGaN/GaN high-electron-mobility transistors. *Journal of Applied Physics*, **2019**, 125, 151614	2.5	5
265	3D Fourier imaging based on 2D heterodyne detection at THz frequencies. *APL Photonics*, **2019**, 4, 106108	5.2	8
264	300-GHz in-line holography with high dynamic range **2019**,		1
263	Fourier imaging with CW terahertz waves **2019**,		1
262	300-GHz holography with heterodyne detection **2019**,		1
261	Nonlocal collective ultrastrong interaction of plasmonic metamaterials and photons in a terahertz photonic crystal cavity. *Optics Express*, **2019**, 27, 24455-24468	3.3	8

260	Circuit-Based Hydrodynamic Modeling of AlGaN/GaN HEMTs **2019**,		2
259	Direct Near-Field Observation of Surface Plasmon Polaritons on Silver Nanowires. *ACS Omega*, **2019**, 4, 21962-21966	3.9	9
258	TeraFET multi-pixel THz array for a confocal imaging system **2019**,		2
257	Coherent photo-induced phonon emission in the charge-density-wave state of K0.3MoO3. *New Journal of Physics*, **2019**, 21, 013013	2.9	0
256	Correction to Broadband Terahertz Power Detectors Based on 90-nm Silicon CMOS Transistors With Flat Responsivity Up to 2.2 THz [Sep 18 1413-1416]. *IEEE Electron Device Letters*, **2019**, 40, 354-354	4.4	
255	Terahertz Detection With a Low-Cost Packaged GaAs High-Electron-Mobility Transistor. *IEEE Transactions on Terahertz Science and Technology*, **2019**, 9, 27-37	3.4	7
254	Field-effect transistors as electrically controllable nonlinear rectifiers for the characterization of terahertz pulses. *APL Photonics*, **2018**, 3, 051705	5.2	12
253	Towards gas sensing with vertically aligned carbon nanotubes interrogated by THz radiation pulses. *Lithuanian Journal of Physics*, **2018**, 58,	1.1	4
252	Dielectric properties of vertically aligned multi-walled carbon nanotubes in the terahertz and mid-infrared range. *Journal Physics D: Applied Physics*, **2018**, 51, 034004	3	10
251	Imaging and Spectroscopic Sensing with Low-Repetition-Rate Terahertz Pulses and GaN TeraFET Detectors. *Journal of Infrared, Millimeter, and Terahertz Waves*, **2018**, 39, 262-272	2.2	7
250	Anisotropic excitation of surface plasmon polaritons on a metal film by a scattering-type scanning near-field microscope with a non-rotationally-symmetric probe tip. *Nanophotonics*, **2018**, 7, 269-276	6.3	20
249	Direct near-field mapping of nano-sphere-excited leaky surface modes atanisotropic metasurface. *Journal of Physics: Conference Series*, **2018**, 1092, 012165	0.3	
248	Near-Field Observation of Guided-Mode Resonances on a Metasurface via Dielectric Nanosphere Excitation. *ACS Photonics*, **2018**, 5, 4238-4243	6.3	2
247	Field-Effect Transistor Based Detectors for Power Monitoring of THz Quantum Cascade Lasers. *IEEE Transactions on Terahertz Science and Technology*, **2018**, 8, 613-621	3.4	17
246	Sub-picosecond pulsed THz FET detector characterization in plasmonic detection regime based on autocorrelation technique. *Semiconductor Science and Technology*, **2018**, 33, 124013	1.8	8
245	Broadband Terahertz Power Detectors Based on 90-nm Silicon CMOS Transistors With Flat Responsivity Up to 2.2 THz. *IEEE Electron Device Letters*, **2018**, 39, 1413-1416	4.4	36
244	Thermal noise-limited sensitivity of FET-based terahertz detectors **2017**,		6
243	Phase-channel dynamics reveal the role of impurities and screening in a quasi-one-dimensional charge-density wave system. *Scientific Reports*, **2017**, 7, 2039	4.9	8

242	Hydrodynamic modelling of terahertz rectification in AlGaN/GaN high electron mobility transistors. *Journal of Physics: Conference Series*, **2017**, 906, 012023	0.3	5
241	Efficient Detection of 3 THz Radiation from Quantum Cascade Laser Using Silicon CMOS Detectors. *Journal of Infrared, Millimeter, and Terahertz Waves*, **2017**, 38, 1183-1188	2.2	9
240	Enhanced performance of AlGaN/GaN HEMT-Based THz detectors at room temperature and at low temperature **2017**,		1
239	0.25-$muhbox{m}$ GaN TeraFETs Optimized as THz Power Detectors and Intensity-Gradient Sensors. *IEEE Transactions on Terahertz Science and Technology*, **2016**, 6, 348-350	3.4	30
238	Saturable absorption of femtosecond optical pulses in multilayer turbostratic graphene. *Optics Express*, **2016**, 24, 15261-73	3.3	7
237	Optimization of the Design of Terahertz Detectors Based on Si CMOS and AlGaN/GaN Field-Effect Transistors. *International Journal of High Speed Electronics and Systems*, **2016**, 25, 1640013	0.5	10
236	How good would the conductivity of graphene have to be to make single-layer-graphene metamaterials for terahertz frequencies feasible?. *Carbon*, **2015**, 94, 301-308	10.4	30
235	Camera for High-Speed THz Imaging. *Journal of Infrared, Millimeter, and Terahertz Waves*, **2015**, 36, 986-997	2.2	27
234	The potential for sensitivity enhancement by the thermoelectric effect in carbon-nanotube and graphene Tera-FETs. *Journal of Physics: Conference Series*, **2015**, 647, 012004	0.3	8
233	Relativistic Doppler reflection as a probe for the initial relaxation of a non-equilibrium electron-hole plasma in silicon. *Journal of Physics: Conference Series*, **2015**, 647, 012016	0.3	0
232	High-sensitivity wideband THz detectors based on GaN HEMTs with integrated bow-tie antennas **2015**,		13
231	Terahertz rectification by plasmons and hot carriers in gated 2D electron gases **2015**,		4
230	Ultrafast dynamic conductivity and scattering rate saturation of photoexcited charge carriers in silicon investigated with a midinfrared continuum probe. *Physical Review B*, **2015**, 91,	3.3	11
229	Exploration of Terahertz Imaging with Silicon MOSFETs. *Journal of Infrared, Millimeter, and Terahertz Waves*, **2014**, 35, 63-80	2.2	52
228	Antenna-integrated 0.6 THz FET direct detectors based on CVD graphene. *Nano Letters*, **2014**, 14, 5834-8	11.5	137
227	20 μm gate width CVD graphene FETs for 0.6 THz detection **2014**,		1
226	9.74-THz electronic Far-Infrared detection using Schottky barrier diodes in CMOS **2014**,		11
225	Antenna-coupled field-effect transistors for multi-spectral terahertz imaging up to 4.25 THz. *Optics Express*, **2014**, 22, 19235-41	3.3	89

224	Relativistic Doppler frequency upconversion of terahertz pulses reflecting from a photoinduced plasma front in silicon. *Physical Review B*, **2014**, 90,	3.3	10
223	THz Active Imaging Systems with Real-Time Capabilities. *NATO Science for Peace and Security Series B: Physics and Biophysics*, **2014**, 153-187	0.2	4
222	Heterodyne and subharmonic mixing at 0.6 THz in an AlGaAs/InGaAs/AlGaAs heterostructure field effect transistor. *Applied Physics Letters*, **2013**, 103, 093505	3.4	8
221	Spatio-spectral characteristics of ultra-broadband THz emission from two-colour photoexcited gas plasmas and their impact for nonlinear spectroscopy. *New Journal of Physics*, **2013**, 15, 075023	2.9	42
220	Real-time CMOS terahertz camera employing plane-to-plane imaging with a focal-plane array of field-effect transistors **2013**,		5
219	Terahertz frequency upconversion via relativistic Doppler reflection from a photoinduced plasma front in a solid-state medium. *Physical Review B*, **2013**, 87,	3.3	14
218	Terahertz responsivity and low-frequency noise in biased silicon field-effect transistors. *Applied Physics Letters*, **2013**, 102, 153505	3.4	75
217	. *IEEE Sensors Journal*, **2013**, 13, 124-132	4	35
216	Optimized Tera-FET detector performance based on an analytical device model verified up to 9 THz **2013**,		4
215	Broadband terahertz spectroscopy: principles, fundamental research and potential for industrial applications. *European Journal of Physics*, **2013**, 34, S179-S199	0.8	31
214	Terahertz array imagers: towards the implementation of terahertz cameras with plasma-wave-based silicon MOSFET detectors **2013**, 231-271		5
213	Optimization of single-cycle terahertz generation in LiNbO3 for sub-50 femtosecond pump pulses. *Optics Express*, **2013**, 21, 6826-36	3.3	24
212	Recovery of ultra-broadband terahertz pulses from sum-frequency spectrograms using a generalized deconvolution method. *EPJ Web of Conferences*, **2013**, 41, 09011	0.3	4
211	Broadside-coupled triangular split-ring-resonators for terahertz sensing. *EPJ Applied Physics*, **2013**, 61, 30402	1.1	17
210	CMOS detector arrays for coherent THz imaging: From point-to-point towards plane-to-plane imaging configurations **2012**,		1
209	Heterodyne and spectroscopic room temperature terahertz imaging using InGaAs bow-tie diodes **2012**,		1
208	Terahertz sensing application by using planar split-ring-resonator structures. *Microsystem Technologies*, **2012**, 18, 2071-2076	1.7	37
207	CMOS integrated antenna-coupled field-effect-transistors for the detection of 0.2 to 4.3 THz **2012**,		8

206	Terahertz detection and coherent imaging from 0.2 to 4.3 THz with silicon CMOS field-effect transistors **2012**,		3
205	Detectors for terahertz multi-pixel coherent imaging and demonstration of real-time imaging with a 12x12-pixel CMOS array **2012**,		9
204	Electric field distribution in biased GaAs microstructures with field-pinning layers. *Superlattices and Microstructures*, **2012**, 52, 1143-1154	2.8	1
203	. *IEEE Transactions on Microwave Theory and Techniques*, **2012**, 60, 3834-3843	4.1	147
202	Effect of the Metallization on the Resonances of THz Fishnet Metamaterials. *Journal of the European Optical Society-Rapid Publications*, **2012**, 7,	2.5	8
201	DESIGN OF A TERAHERTZ POLARIZATION ROTATOR BASED ON A PERIODIC SEQUENCE OF CHIRAL-METAMATERIAL AND DIELECTRIC SLABS. *Progress in Electromagnetics Research*, **2012**, 124, 301-314	3.8	38
200	Dual-band polarization-independent sub-terahertz fishnet metamaterial. *Current Applied Physics*, **2012**, 12, 443-450	2.6	29
199	Towards monolithically integrated CMOS cameras for active imaging with 600 GHz radiation **2012**,		3
198	CMOS detector arrays in a virtual 10-kilopixel camera for coherent terahertz real-time imaging. *Optics Letters*, **2012**, 37, 536-8	3	43
197	Terahertz Sensing and Imaging with Silicon Field-Effect Transistors up to 9 THz **2012**,		2
196	Silicon CMOS-transistor-based detection up to 4.25 THz **2011**,		5
195	Performance and performance variations of sub-1 THz detectors fabricated with 0.15 [micro sign]m CMOS foundry process. *Electronics Letters*, **2011**, 47, 661	1.1	50
194	Experimental demonstration of efficient pulsed terahertz emission from a stacked GaAs/AlGaAs p-i-n-i heterostructure. *Applied Physics Letters*, **2011**, 98, 091103	3.4	13
193	Terahertz heterodyne imaging with InGaAs-based bow-tie diodes. *Applied Physics Letters*, **2011**, 99, 131101	3.4	34
192	. *IEEE Transactions on Terahertz Science and Technology*, **2011**, 1, 183-200	3.4	152
191	Numerical and experimental investigation of fishnet-based metamaterial in a X-band waveguide. *Journal Physics D: Applied Physics*, **2011**, 44, 255101	3	21
190	Silicon CMOS-based THz detection **2011**,		3
189	Terahertz propagation properties of free-standing woven-steel-mesh metamaterials: Pass-bands and signatures of abnormal group velocities. *Journal of Applied Physics*, **2011**, 110, 064902	2.5	7

188	Strong Electric Field Driven Carrier Transport Non-Linearities in n-Type GaAs/AlGaAs Superlattices. *Acta Physica Polonica A*, **2011**, 119, 167-169	0.6	1
187	Hybrid Continuous-Wave Demodulating Multipixel Terahertz Imaging Systems. *IEEE Transactions on Microwave Theory and Techniques*, **2010**, 58, 2022-2026	4.1	6
186	Terahertz heterodyne detection with silicon field-effect transistors. *Applied Physics Letters*, **2010**, 96, 042106	3.4	69
185	Illumination Aspects in Active Terahertz Imaging. *IEEE Transactions on Microwave Theory and Techniques*, **2010**, 58, 2008-2013	4.1	22
184	Redox-Active Ferrocenylboronium Polyelectrolytes with Main Chain Charge-Transfer Structure. *Macromolecules*, **2010**, 43, 5256-5261	5.5	26
183	Phase-locking of the beat signal of two distributed-feedback diode lasers to oscillators working in the MHz to THz range. *Optics Express*, **2010**, 18, 8621-9	3.3	27
182	Coherent electro-optical detection of terahertz radiation from an optical parametric oscillator. *Optics Express*, **2010**, 18, 11316-26	3.3	13
181	Terahertz white-light pulses from an air plasma photo-induced by incommensurate two-color optical fields. *Optics Express*, **2010**, 18, 23173-82	3.3	148
180	Pump/probe THz spectroscopy of the conductivity of TTF-TCNQ films **2010**,		1
179	A CMOS focal-plane array for heterodyne terahertz imaging **2009**,		20
178	Fast active THz-camera with global illumination **2009**,		3
177	Magnetic-field-enhanced transient and stationary drift currents of oscillating Bloch electrons in superlattices and limits of average-particle description in relation to Monte Carlo simulations. *Physical Review B*, **2009**, 80,	3.3	3
176	Active THz imaging system with improved frame rate **2009**,		3
175	Fast active THz camera with range detection by frequency modulation **2009**,		6
174	Synthesis, structure, photoluminescence and photoreactivity of 2,3-diphenyl-4-neopentyl-1-silacyclobut-2-enes. *Chemistry - A European Journal*, **2009**, 15, 8625-45	4.8	11
173	Fast Active THz Cameras with Ranging Capabilities. *Journal of Infrared, Millimeter, and Terahertz Waves*, **2009**, 30, 1281	2.2	27
172	Terahertz Imaging Detectors in CMOS Technology. *Journal of Infrared, Millimeter, and Terahertz Waves*, **2009**, 30, 1269	2.2	23
171	A 0.65 THz Focal-Plane Array in a Quarter-Micron CMOS Process Technology. *IEEE Journal of Solid-State Circuits*, **2009**, 44, 1968-1976	5.5	276

170	Terahertz heterodyne detection with silicon CMOS transistors **2009**,		3
169	High signal-to-noise-ratio electro-optical terahertz imaging system based on an optical demodulating detector array. *Optics Letters*, **2009**, 34, 3424-6	3	17
168	Characterizing large-area electro-optic crystals toward two-dimensional real-time terahertz imaging. *Applied Optics*, **2009**, 48, 5197-204	0.2	4
167	Rational design of high-responsivity detectors of terahertz radiation based on distributed self-mixing in silicon field-effect transistors. *Journal of Applied Physics*, **2009**, 105, 114511	2.5	202
166	Terahertz imaging with Si MOSFET focal-plane arrays **2009**,		30
165	Quasioptical system design **2009**,		2
164	Efficient distributed self-mixing in silicon CMOS transistors **2009**,		1
163	Diagnosing water content in paper by terahertz radiation. *Optics Express*, **2008**, 16, 9060-6	3.3	95
162	Terahertz profilometry at 600 GHz with 0.5 microm depth resolution. *Optics Express*, **2008**, 16, 11289-93	3.3	30
161	Examining the terahertz signal from a photoexcited biased semiconductor superlattice for evidence of gain. *Applied Physics Letters*, **2008**, 93, 021122	3.4	5
160	Berührungsfreie Prüfung von Materialoberflächen mit THz-Strahlung (Contactless Testing of the Surface of Materials). *TM Technisches Messen*, **2008**, 75, 45-50	0.7	2
159	Concept of internal mixing in semiconductor lasers and optical amplifiers for room-temperature generation of tunable continuous terahertz waves. *Physica E: Low-Dimensional Systems and Nanostructures*, **2008**, 40, 1968-1970	3	
158	Electron ensemble coherence and terahertz radiation amplification in a cascade superlattice structure. *Microelectronics Journal*, **2008**, 39, 624-627	1.8	2
157	Terahertz imaging with GaAs field-effect transistors. *Electronics Letters*, **2008**, 44, 408	1.1	46
156	Few-Cycle Laser Pulses: The Carrier-Envelope Phase, Its Role in the THz Emission from Laser-Generated Plasmas and a New Way to Measure It. *Acta Physica Polonica A*, **2008**, 113, 769-776	0.6	3
155	Evidence for long-living charge carriers in electrically biased low-temperature-grown GaAs photoconductive switches. *Applied Physics Letters*, **2007**, 90, 052101	3.4	13
154	Continuous-wave terahertz imaging with a hybrid system. *Applied Physics Letters*, **2007**, 90, 091111	3.4	68
153	Broadband THz emission from gas plasmas induced by femtosecond optical pulses: From fundamentals to applications. *Laser and Photonics Reviews*, **2007**, 1, 349-368	8.3	359

152	Characterization of Fe(II) complexes exhibiting the ligand-driven light-induced spin-change effect using SQUID and magnetic circular dichroism. *Comptes Rendus Chimie*, **2007**, 10, 125-136	2.7	15
151	CARRIER-DENSITY DEPENDENCE OF THE EXCHANGE COUPLING BETWEEN MAGNETIC IONS AND CONDUCTION BAND ELECTRONS IN HEAVILY n-TYPE Zn(1-x)MnxSe AND OPTICALLY PUMPED Cd(1-x)MnxTe. *International Journal of Modern Physics B*, **2007**, 21, 1632-1637	1.1	1
150	Continuous-wave terahertz imaging with a hybrid system **2007**,		3
149	Towards an active real-time THz camera: first realization of a hybrid system **2007**,		6
148	All-Optoelectronic Terahertz Imaging Systems and Examples of Their Application. *Proceedings of the IEEE*, **2007**, 95, 1576-1582	14.3	13
147	Radiation field screening in photoconductive antennae studied via pulsed terahertz emission spectroscopy. *Applied Physics Letters*, **2007**, 91, 232506	3.4	51
146	Ballistic transport in semiconductor nanostructures: From quasi-classical oscillations to novel THz-emitters **2006**, 67, 199-205		
145	The coherent Hall effect of charge carriers in a superlattice: semiclassical description of the wavepacket dynamics. *Journal of Physics Condensed Matter*, **2006**, 18, 2487-2509	1.8	3
144	Motional-narrowing-type dephasing of electron and hole spins of itinerant excitons in magnetically doped II-VI bulk semiconductors. *Physical Review Letters*, **2006**, 96, 117203	7.4	15
143	Silicon lens-coupled bow-tie InGaAs-based broadband terahertz sensor operating at room temperature. *Electronics Letters*, **2006**, 42, 825	1.1	38
142	Ultrafast Fiske effect in semiconductor superlattices. *Physical Review Letters*, **2006**, 96, 137403	7.4	20
141	Generation of a DC Fiske current by coupling of Bloch and in-plane cyclotron oscillations in a semiconductor superlattice. *Physica Status Solidi (B): Basic Research*, **2006**, 243, 2405-2409	1.3	2
140	Determination of the carrier-envelope phase of few-cycle laser pulses with terahertz-emission spectroscopy. *Nature Physics*, **2006**, 2, 327-331	16.2	192
139	Comparative performance of terahertz emitters in amplifier-laser-based systems. *Semiconductor Science and Technology*, **2005**, 20, S134-S141	1.8	51
138	Large-area electro-optic ZnTe terahertz emitters. *Optics Express*, **2005**, 13, 5353-62	3.3	113
137	A Quantum Optical XOR Gate **2005**, 418-424		
136	Spin-conserving carrier recombination in conjugated polymers. *Nature Materials*, **2005**, 4, 340-6	27	167
135	Picosecond energy relaxation in. *Physica B: Condensed Matter*, **2005**, 359-361, 1297-1299	2.8	2

134	The evolution of the electric field in an optically excited semiconductor superlattice. *Physica Status Solidi C: Current Topics in Solid State Physics*, **2005**, 2, 3055-3058		
133	THz-emitter based on ballistic transport in nano-pin diodes. *Physica Status Solidi (A) Applications and Materials Science*, **2005**, 202, 965-969	1.6	3
132	Electro-optic investigation of the Coherent Hall Effect in semiconductor superlattices. *Physica Status Solidi (B): Basic Research*, **2005**, 242, 1175-1178	1.3	6
131	THz-photomixer based on quasi-ballistic transport. *Semiconductor Science and Technology*, **2005**, 20, S178-S190	1.8	41
130	Time-resolved photocurrent spectroscopy of the evolution of the electric field in optically excited superlattices and the prospects for Bloch gain. *Applied Physics Letters*, **2005**, 86, 102103	3.4	11
129	Efficient Terahertz Pulse Generation in Laser-Induced Gas Plasmas. *Acta Physica Polonica A*, **2005**, 107, 99-108	0.6	28
128	Ultrafast Optical and Magneto-Optical Dynamics in Colossal-Magnetoresistance Manganites. *Acta Physica Polonica A*, **2005**, 107, 211-214	0.6	
127	Dynamics of the Electric Field in a GaAs/AlGaAs Superlattice after Femtosecond Optical Excitation: Application of Time-Resolved Spectroscopic Techniques. *Acta Physica Polonica A*, **2005**, 107, 250-255	0.6	
126	Microwave sensor based on modulation-doped GaAs/AlGaAs structure. *Semiconductor Science and Technology*, **2004**, 19, S436-S439	1.8	11
125	Detection of terahertz□sub-terahertz radiation by asymmetrically-shaped 2DEG layers. *Electronics Letters*, **2004**, 40, 631	1.1	21
124	Field Screening in Low-Temperature-Grown GaAs Photoconductive Antennas. *Japanese Journal of Applied Physics*, **2004**, 43, 1038-1043	1.4	24
123	On the way to □optical doping□ of electronically low-dimensional polymer systems with strong charge and spin correlations. *Applied Physics A: Materials Science and Processing*, **2004**, 78, 477-481	2.6	2
122	Electronic Structure, Photophysics, and Relaxation Dynamics of Charge Transfer Excited States in Boron□Nitrogen-Bridged Ferrocene-Donor Organic-Acceptor Compounds. *Journal of Physical Chemistry A*, **2004**, 108, 3281-3291	2.8	21
121	Mode calculations for a terahertz quantum cascade laser. *Optics Express*, **2004**, 12, 2062-9	3.3	8
120	All-optoelectronic continuous-wave terahertz systems. *Philosophical Transactions Series A, Mathematical, Physical, and Engineering Sciences*, **2004**, 362, 263-79; discussion 279-81	3	9
119	Terahertz-pulse generation by photoionization of air with laser pulses composed of both fundamental and second-harmonic waves. *Optics Letters*, **2004**, 29, 1120-2	3	331
118	Optical far-IR wave generation - state-of-the-art and advanced device structures **2004**,		3
117	Carrier-Density Dependence of Faraday Rotation and Spin Splitting in Cd1□ Mn x Te. *Journal of Superconductivity and Novel Magnetism*, **2003**, 16, 461-464		1

116	High-frequency oscillations in an Si/Si(p)/Si(n) device. *Chaos, Solitons and Fractals*, **2003**, 17, 289-295	9.3	3
115	Giga- and terahertz frequency band detector based on an asymmetrically necked n-n+-GaAs planar structure. *Journal of Applied Physics*, **2003**, 93, 3034-3038	2.5	21
114	Terahertz optical properties of thin doped contact layers in GaAs device structures. *Semiconductor Science and Technology*, **2003**, 18, 28-32	1.8	3
113	Remote identification of protrusions and dents on surfaces by terahertz reflectometry with spatial beam filtering and out-of-focus detection. *Applied Physics Letters*, **2003**, 83, 3996-3998	3.4	33
112	Influence of a strong magnetic field on the Wannier-Stark states of an electrically biased GaAs/AlxGa1As superlattice. *Physical Review B*, **2003**, 67,	3.3	6
111	The Hall Current of Coherent Electron Wavepackets. *Springer Series in Chemical Physics*, **2003**, 353-355	0.3	
110	All-Optoelectronic CW THz Imaging for Tumor Recognition. *Springer Series in Chemical Physics*, **2003**, 280-282	0.3	
109	THz generation by third-order non-linearities in air and air plasmas. *Springer Series in Chemical Physics*, **2003**, 274-276	0.3	1
108	Visualization and classification in biomedical terahertz pulsed imaging. *Physics in Medicine and Biology*, **2002**, 47, 3847-52	3.8	55
107	Photoconductivity of Regular Low Dimensional Arrays of GaAs Wires. *Materials Science Forum*, **2002**, 384-385, 87-90	0.4	
106	GHz-THz Detection by Asymmetrically-Shaped GaAs: Bulk Material versus Nanostructures. *Materials Science Forum*, **2002**, 384-385, 193-196	0.4	
105	Magnetotransport in Low Dimensional Honeycomb-Shape GaAs Networks. *Materials Science Forum*, **2002**, 384-385, 59-62	0.4	
104	Indium tin oxide-coated glass as dichroic mirror for far-infrared electromagnetic radiation. *Journal of Applied Physics*, **2002**, 92, 2210-2212	2.5	48
103	All-optoelectronic continuous wave THz imaging for biomedical applications. *Physics in Medicine and Biology*, **2002**, 47, 3743-8	3.8	66
102	Free-carrier dynamics in low-temperature-grown GaAs at high excitation densities investigated by time-domain terahertz spectroscopy. *Physical Review B*, **2002**, 65,	3.3	47
101	Continuous-wave all-optoelectronic terahertz imaging. *Applied Physics Letters*, **2002**, 80, 3003-3005	3.4	160
100	Gas-pressure dependence of terahertz-pulse generation in a laser-generated nitrogen plasma. *Journal of Applied Physics*, **2002**, 91, 2611-2614	2.5	63
99	Coherent Hall effect in a semiconductor superlattice. *Physical Review Letters*, **2002**, 88, 086801	7.4	18

98	Optical determination of the oxygen content of YBa2Cu3O6+x thin films by IR reflectance and transmittance measurements. *Physica C: Superconductivity and Its Applications*, **2001**, 366, 63-72	1.3	4
97	Introduction to the issue on ultrafast phenomena and their applications. *IEEE Journal of Selected Topics in Quantum Electronics*, **2001**, 7, 501-503	3.8	
96	Experimental evidence for electron repulsion in multiphoton double ionization. *Journal of Physics B: Atomic, Molecular and Optical Physics*, **2001**, 34, L449-L455	1.3	36
95	Terahertz dark-field imaging of biomedical tissue. *Optics Express*, **2001**, 9, 616-21	3.3	137
94	THz generation by photo-ionization of electrically biased air. *Springer Series in Chemical Physics*, **2001**, 200-202	0.3	1
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